



General description

Low capacitance bidirectional ElectroStatic Discharge (ESD) protection diode in a DFN1006(SOD882) leadless ultra small Surface-Mounted Device (SMD) plastic package designed to protect one signal line from the damage caused by ESD and other transients.

Features and benefits

- Low Capacitance 2.8 pF(Typ)
- Reverse stand-off voltage: 5V Max
- Low leakage current: nA Level
- Response time is typically < 1 ns
- IEC61000-4-2 Level 4 ESD Protection

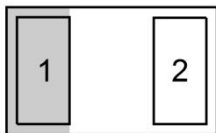
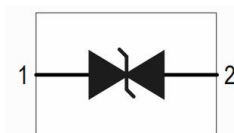
Application information

- Cellular Handsets & Accessories
- Digital Cameras
- Peripherals
- Keypads, Side Keys, USB 2.0, LCD Displays
- MP3 Players
- Portable Instrumentation
- Notebooks & Desktop Computers

Ordering information

Device	Package	Packaging	Reel Size
SLESD8LM5.0CS	DFN1006-2L	10000/Tape & Reel	7 Inch

Schematic & Pin configuration

Simplified outline	Graphic symbol
	

Maximum Ratings ($T_{OP} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)

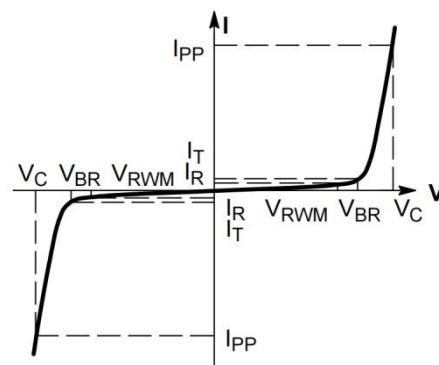
Parameter	Symbol	Value	Unit
Peak Pulse Power ($T_p = 8/20\text{ }\mu\text{s}$)	P_{PPM}	53	W
Rated Peak Pulse Current ($T_p = 8/20\text{ }\mu\text{s}$)	I_{PPM}	3.5	A
ESD voltage IEC 61000-4-2 (air discharge)	V_{ESD}	25	kV
ESD voltage IEC 61000-4-2 (contact discharge)	V_{ESD}	25	kV
Maximum lead temperature for soldering during 10s	T_L	260	$^{\circ}\text{C}$
Storage Temperature Range	T_{stg}	-55 to +150	$^{\circ}\text{C}$
Operating Temperature Range	T_{OP}	-40 to +125	$^{\circ}\text{C}$
Maximum junction temperature	T_j	150	$^{\circ}\text{C}$

Electrical Characteristics ($T_{OP} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)

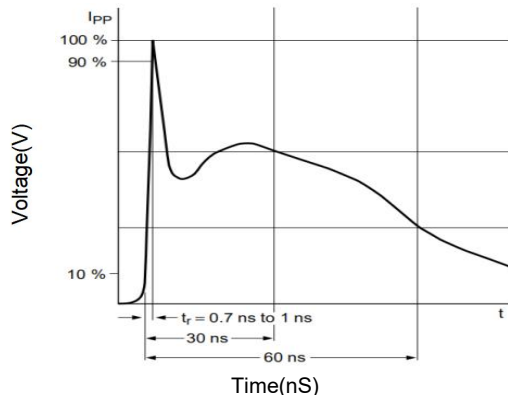
Parameter	Symbol	Min	Typ	Max	Unit	Condition
Reverse Working Voltage	V_{RWM}	--	--	5.0	V	
Breakdown Voltage	V_{BR}	7.0	--	9.0	V	$I_T=1\text{mA}$
Leakage Current I_{Leak}	I_R	--	--	100	nA	$V_{RWM}=5\text{V}$
Clamping Voltage	V_C	--	10.0	12.0	V	$I_{pp}=1.0\text{A}, T_p=8/20\mu\text{s}$
		--	14.0	15.0	V	$I_{pp}=3.5\text{A}, T_p=8/20\mu\text{s}$
Junction Capacitance	C_j	--	2.8	3.2	pF	$V_R=0\text{V}, f=1\text{MHz}$
		--	2.0	2.5	pF	$V_R=5.0\text{V}, f=1\text{MHz}$

Portion Electronics Parameter

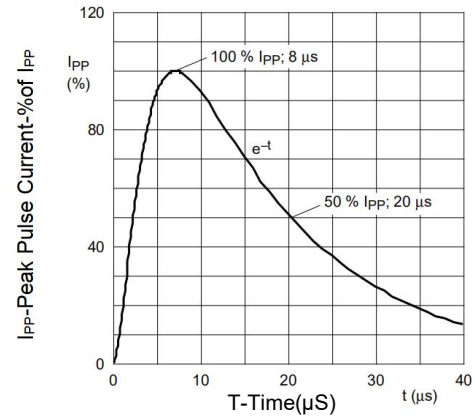
Symbol	Parameter
I_{PP}	Reverse Peak Pulse Current
V_C	Clamping Voltage @ I_{PP}
V_{RWM}	Working Peak Reverse Voltage
I_R	Reverse Leakage Current @ V_{RWM}
V_{BR}	Breakdown Voltage @ I_T
I_T	V_{BR} Test Current



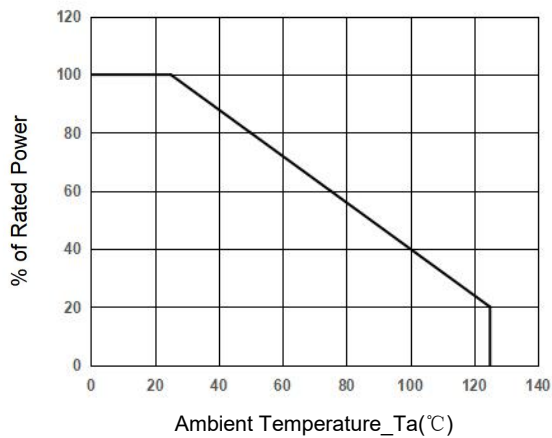
Typical Performance Characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise Specified)



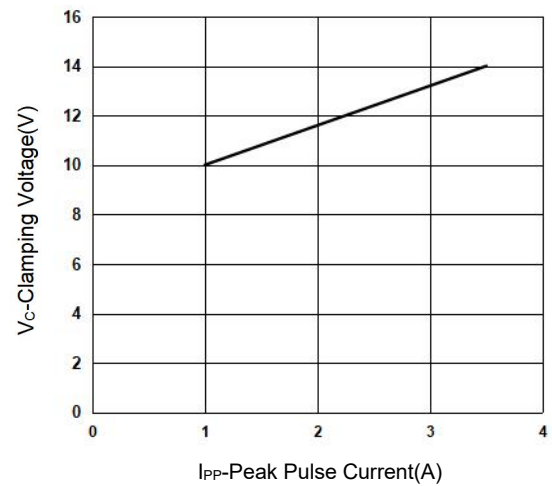
IEC61000-4-2 Pulse Waveform



IEC61000-4-5 8X20 μs Pulse Waveform

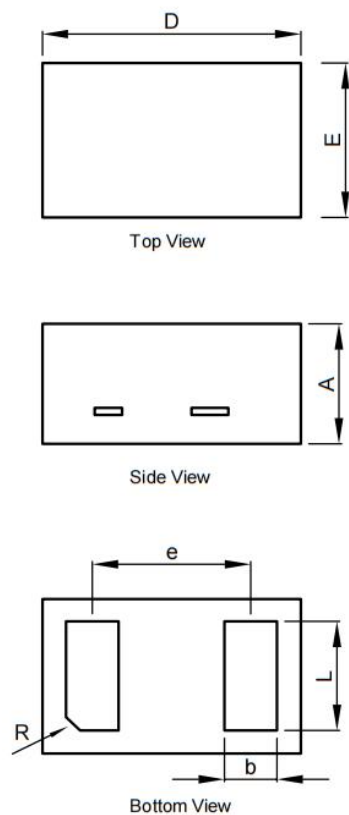


Power Derating Curve



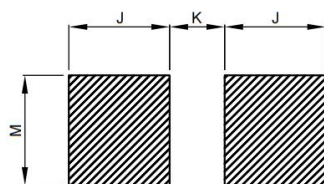
Clamping Voltage vs. Peak Pulse Current

Package Outline Dimensions (DFN1006-2L)



SYMBOL	MILLIMETERS		
	MIN	TYP	MAX
A	0.45	0.50	0.55
D	0.95	1.00	1.05
E	0.55	0.60	0.65
b	0.20	0.25	0.30
L	0.45	0.50	0.55
e	0.675		
R	0.07	0.10	0.13

Soldering Footprint (mm)



SYMBOL	MILLIMETERS	
	MIN	MAX
J	0.50	0.60
K	0.25	0.35
M	0.55	0.65

Ordering information

Package	Reel Size	Packaging (pcs)
DFN1006-2L	7 Inch	10000/Tape & Reel